

74HC243

Quad bus transceiver; 3-state

Rev. 03 — 12 November 2004

Product data sheet

1. General description

The 74HC243 is a high-speed Si-gate CMOS device and is pin compatible with low power Schottky TTL (LSTTL). The 74HC243 is specified in compliance with JEDEC standard no. 7A.

The 74HC243 is a quad bus transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The 74HC243 is designed for 4-line asynchronous 2-way data communications between data buses.

The output enable inputs (\overline{OEA} and OEB) can be used to isolate the buses.

The 74HC243 is similar to the 74HC242 but has non-inverting (true) outputs.

2. Features

- Non-inverting 3-state outputs
- 2-way asynchronous data bus communication
- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM EIA/JESD22-A114-B exceeds 2000 V
 - ◆ MM EIA/JESD22-A115-A exceeds 200 V.
- Multiple package options
- Specified from -40°C to $+80^{\circ}\text{C}$ and from -40°C to $+125^{\circ}\text{C}$.

PHILIPS

3. Quick reference data

Table 1: Quick reference dataGND = 0 V; T_{amb} = 25 °C; $t_r = t_f = 6 \text{ ns}$.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit | |
|--------------------|--|---|-----|-----|-----|------|----|
| t_{PHL}, t_{PLH} | propagation delay An to Bn; Bn to An | $C_L = 15 \text{ pF}; V_{CC} = 5 \text{ V}$ | - | 6 | - | ns | |
| C_I | input capacitance | | - | 3.5 | - | pF | |
| $C_{I/O}$ | input/output capacitance | | - | 10 | - | pF | |
| C_{PD} | power dissipation capacitance per transceiver | $V_I = \text{GND to } V_{CC}$ | [1] | - | 26 | - | pF |

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

4. Ordering information

Table 2: Ordering information

| Type number | Package | | | | Version |
|-------------|-------------------|--------|--|----------|---------|
| | Temperature range | Name | Description | Version | |
| 74HC243N | −40 °C to +125 °C | DIP14 | plastic dual in-line package; 14 leads (300 mil) | SOT27-1 | |
| 74HC243D | −40 °C to +125 °C | SO14 | plastic small outline package; 14 leads; body width 3.9 mm | SOT108-1 | |
| 74HC243DB | −40 °C to +125 °C | SSOP14 | plastic shrink small outline package; 14 leads; body width 5.3 mm | SOT337-1 | |

5. Functional diagram

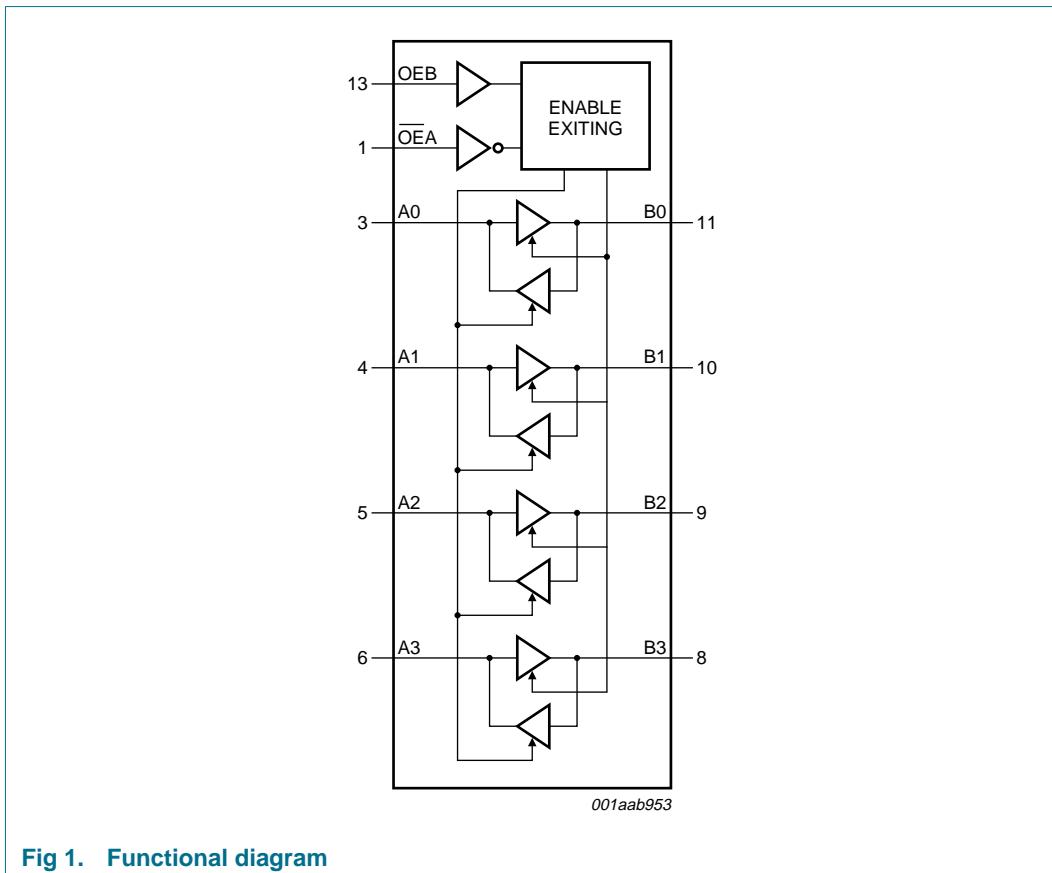


Fig 1. Functional diagram

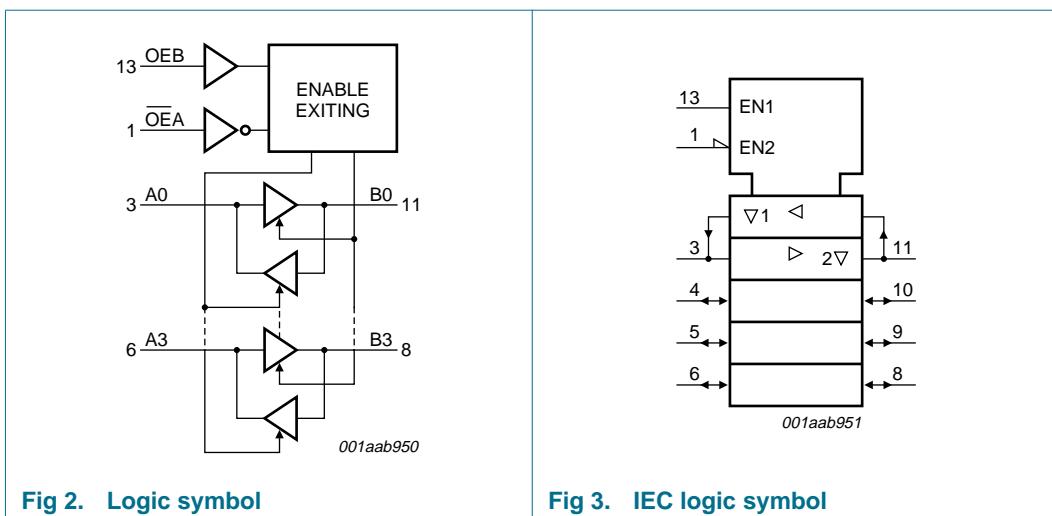


Fig 2. Logic symbol

Fig 3. IEC logic symbol

6. Pinning information

6.1 Pinning

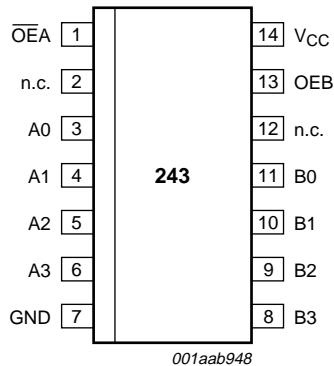


Fig 4. Pin configuration

6.2 Pin description

Table 3: Pin description

| Symbol | Pin | Description |
|-----------------|-----|----------------------------------|
| OE _A | 1 | output enable input (active LOW) |
| n.c. | 2 | not connected |
| A ₀ | 3 | data input or output |
| A ₁ | 4 | data input or output |
| A ₂ | 5 | data input or output |
| A ₃ | 6 | data input or output |
| GND | 7 | ground (0 V) |
| B ₃ | 8 | data output or input |
| B ₂ | 9 | data output or input |
| B ₁ | 10 | data output or input |
| B ₀ | 11 | data output or input |
| n.c. | 12 | not connected |
| OEB | 13 | output enable input |
| V _{CC} | 14 | positive supply voltage |

7. Functional description

7.1 Function table

Table 4: Function table [1]

| Control | | Input or output | |
|---------|-----|-----------------|-------|
| OEA | OEB | An | Bn |
| L | L | input | B = A |
| H | L | Z | Z |
| L | H | Z | Z |
| H | H | A = B | input |

[1] H = HIGH voltage level;
L = LOW voltage level;
Z = high-impedance OFF-state.

8. Limiting values

Table 5: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-------------------|-------------------------------|---|------|----------|--------|
| V_{CC} | supply voltage | | -0.5 | +7 | V |
| I_{IK} | input diode current | $V_I < -0.5$ V or $V_I > V_{CC} + 0.5$ V | - | ± 20 | mA |
| I_{OK} | output diode current | $V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V | - | ± 20 | mA |
| I_O | output source or sink current | $V_O = -0.5$ V to $V_{CC} + 0.5$ V | - | ± 35 | mA |
| I_{CC}, I_{GND} | V_{CC} or GND current | | - | ± 70 | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_{tot} | power dissipation | | | | |
| | DIP14 package | | [1] | - | 750 mW |
| | SO14 and SSOP16 packages | | [2] | - | 500 mW |

[1] Above 70 °C: P_{tot} derates linearly with 12 mW/K.

[2] Above 70 °C: P_{tot} derates linearly with 8 mW/K.

9. Recommended operating conditions

Table 6: Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|------------|---------------------------|------------------|-----|-----|----------|------|
| V_{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | V |
| V_I | input voltage | | 0 | - | V_{CC} | V |
| V_O | output voltage | | 0 | - | V_{CC} | V |
| t_r, t_f | input rise and fall times | $V_{CC} = 2.0$ V | - | - | 1000 | ns |
| | | $V_{CC} = 4.5$ V | - | 6.0 | 500 | ns |
| | | $V_{CC} = 6.0$ V | - | - | 400 | ns |
| T_{amb} | ambient temperature | | -40 | - | +125 | °C |

10. Static characteristics

Table 7: Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------------------|---------------------------|---|------|------|-----------|---------|
| $T_{amb} = 25$ °C | | | | | | |
| V_{IH} | HIGH-level input voltage | $V_{CC} = 2.0$ V | 1.5 | 1.2 | - | V |
| | | $V_{CC} = 4.5$ V | 3.15 | 2.4 | - | V |
| | | $V_{CC} = 6.0$ V | 4.2 | 3.2 | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 2.0$ V | - | 0.8 | 0.5 | V |
| | | $V_{CC} = 4.5$ V | - | 2.1 | 1.35 | V |
| | | $V_{CC} = 6.0$ V | - | 2.8 | 1.8 | V |
| V_{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = -20 \mu A; V_{CC} = 2.0$ V | 1.9 | 2.0 | - | V |
| | | $I_O = -20 \mu A; V_{CC} = 4.5$ V | 4.4 | 4.5 | - | V |
| | | $I_O = -20 \mu A; V_{CC} = 6.0$ V | 5.9 | 6.0 | - | V |
| | | $I_O = -6.0$ mA; $V_{CC} = 4.5$ V | 3.98 | 4.32 | - | V |
| | | $I_O = -7.8$ mA; $V_{CC} = 6.0$ V | 5.48 | 5.81 | - | V |
| V_{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = 20 \mu A; V_{CC} = 2.0$ V | - | 0 | 0.1 | V |
| | | $I_O = 20 \mu A; V_{CC} = 4.5$ V | - | 0 | 0.1 | V |
| | | $I_O = 20 \mu A; V_{CC} = 6.0$ V | - | 0 | 0.1 | V |
| | | $I_O = 6.0$ mA; $V_{CC} = 4.5$ V | - | 0.15 | 0.26 | V |
| | | $I_O = 7.8$ mA; $V_{CC} = 6.0$ V | - | 0.16 | 0.26 | V |
| I_L | input leakage current | $V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V | - | - | ± 0.1 | μA |
| I_{OZ} | 3-state OFF-state current | $V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 6.0$ V; $V_O = V_{CC}$ or GND | - | - | ± 0.5 | μA |
| I_{CC} | quiescent supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V | - | - | 8.0 | μA |
| C_I | input capacitance | | - | 3.5 | - | pF |
| C_{IO} | input/output capacitance | | - | 10 | - | pF |

Table 7: Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|---------------------------|---|------|-----|------|------|
| T_{amb} = -40 °C to +85 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 2.0 V | 1.5 | - | - | V |
| | | V _{CC} = 4.5 V | 3.15 | - | - | V |
| | | V _{CC} = 6.0 V | 4.2 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 2.0 V | - | - | 0.5 | V |
| | | V _{CC} = 4.5 V | - | - | 1.35 | V |
| | | V _{CC} = 6.0 V | - | - | 1.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 µA; V _{CC} = 2.0 V | 1.9 | - | - | V |
| | | I _O = -20 µA; V _{CC} = 4.5 V | 4.4 | - | - | V |
| | | I _O = -20 µA; V _{CC} = 6.0 V | 5.9 | - | - | V |
| | | I _O = -6.0 mA; V _{CC} = 4.5 V | 3.84 | - | - | V |
| V _{OL} | LOW-level output voltage | I _O = -7.8 mA; V _{CC} = 6.0 V | 5.34 | - | - | V |
| | | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 µA; V _{CC} = 2.0 V | - | - | 0.1 | V |
| | | I _O = 20 µA; V _{CC} = 4.5 V | - | - | 0.1 | V |
| | | I _O = 20 µA; V _{CC} = 6.0 V | - | - | 0.1 | V |
| I _{LI} | input leakage current | I _O = 6.0 mA; V _{CC} = 4.5 V | - | - | 0.33 | V |
| | | I _O = 7.8 mA; V _{CC} = 6.0 V | - | - | 0.33 | V |
| I _{oz} | 3-state OFF-state current | V _I = V _{IH} or V _{IL} ; V _{CC} = 6.0 V; V _O = V _{CC} or GND | - | - | ±5.0 | µA |
| I _{CC} | quiescent supply current | V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V | - | - | 80 | µA |
| T_{amb} = -40 °C to +125 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 2.0 V | 1.5 | - | - | V |
| | | V _{CC} = 4.5 V | 3.15 | - | - | V |
| | | V _{CC} = 6.0 V | 4.2 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 2.0 V | - | - | 0.5 | V |
| | | V _{CC} = 4.5 V | - | - | 1.35 | V |
| | | V _{CC} = 6.0 V | - | - | 1.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | - | | | |
| | | I _O = -20 µA; V _{CC} = 2.0 V | 1.9 | - | - | V |
| | | I _O = -20 µA; V _{CC} = 4.5 V | 4.4 | - | - | V |
| | | I _O = -20 µA; V _{CC} = 6.0 V | 5.9 | - | - | V |
| | | I _O = -6.0 mA; V _{CC} = 4.5 V | 3.7 | - | - | V |
| | | I _O = -7.8 mA; V _{CC} = 6.0 V | 5.2 | - | - | V |

Table 7: Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------------|---------------------------|---|-----|-----|-------|------|
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | - | - | 0.1 | V |
| | | I _O = 20 µA; V _{CC} = 2.0 V | - | - | 0.1 | V |
| | | I _O = 20 µA; V _{CC} = 4.5 V | - | - | 0.1 | V |
| | | I _O = 20 µA; V _{CC} = 6.0 V | - | - | 0.1 | V |
| | | I _O = 6.0 mA; V _{CC} = 4.5 V | - | - | 0.4 | V |
| | | I _O = 7.8 mA; V _{CC} = 6.0 V | - | - | 0.4 | V |
| I _{LI} | input leakage current | V _I = V _{CC} or GND; V _{CC} = 6.0 V | - | - | ±1.0 | µA |
| I _{OZ} | 3-state OFF-state current | V _I = V _{IH} or V _{IL} ; V _{CC} = 6.0 V; V _O = V _{CC} or GND | - | - | ±10.0 | µA |
| I _{CC} | quiescent supply current | V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V | - | - | 160 | µA |

11. Dynamic characteristics

Table 8: Dynamic characteristicsGND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF; R_L = 1000 Ω; see [Figure 8](#).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|--|-----|-----|-----|------|
| T_{amb} = 25 °C | | | | | | |
| t _{PHL} , t _{PLH} | propagation delay An to Bn; Bn to An | see Figure 5 | | | | |
| | | V _{CC} = 2.0 V | - | 22 | 90 | ns |
| | | V _{CC} = 4.5 V | - | 8 | 18 | ns |
| | | V _{CC} = 6.0 V | - | 6 | 15 | ns |
| | | V _{CC} = 5.0 V; C _L = 15 pF | - | 6 | - | ns |
| t _{PZH} , t _{PZL} | 3-state output enable time \overline{OEA} to An or Bn; OEB to An or Bn | see Figure 6 and 7 | | | | |
| | | V _{CC} = 2.0 V | - | 50 | 150 | ns |
| | | V _{CC} = 4.5 V | - | 18 | 30 | ns |
| | | V _{CC} = 6.0 V | - | 14 | 26 | ns |
| t _{PHZ} , t _{PLZ} | 3-state output disable time \overline{OEA} to An or Bn; OEB to An or Bn | see Figure 6 and 7 | | | | |
| | | V _{CC} = 2.0 V | - | 61 | 165 | ns |
| | | V _{CC} = 4.5 V | - | 22 | 33 | ns |
| | | V _{CC} = 6.0 V | - | 18 | 28 | ns |
| t _{THL} , t _{TLH} | output transition time | see Figure 5 | | | | |
| | | V _{CC} = 2.0 V | - | 14 | 60 | ns |
| | | V _{CC} = 4.5 V | - | 5 | 12 | ns |
| | | V _{CC} = 6.0 V | - | 4 | 10 | ns |
| C _{PD} | power dissipation capacitance per transceiver | V _I = GND to V _{CC} | [1] | - | 26 | - |
| T_{amb} = -40 °C to +85 °C | | | | | | |
| t _{PHL} , t _{PLH} | propagation delay An to Bn; Bn to An | see Figure 5 | | | | |
| | | V _{CC} = 2.0 V | - | - | 115 | ns |
| | | V _{CC} = 4.5 V | - | - | 23 | ns |
| | | V _{CC} = 6.0 V | - | - | 20 | ns |

Table 8: Dynamic characteristics ...continued*GND = 0 V; $t_r = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$; $R_L = 1000 \Omega$; see [Figure 8](#).*

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|--|--|-----|-----|-----|------|
| t_{PZH}, t_{PLZ} | 3-state output enable time \overline{OEA} to An or Bn; OEB to An or Bn | see Figure 6 and 7 | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | - | - | 190 | ns |
| | | $V_{CC} = 4.5 \text{ V}$ | - | - | 38 | ns |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | 33 | ns |
| t_{PHZ}, t_{PLZ} | 3-state output disable time \overline{OEA} to An or Bn; OEB to An or Bn | see Figure 6 and 7 | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | - | - | 205 | ns |
| | | $V_{CC} = 4.5 \text{ V}$ | - | - | 41 | ns |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | 35 | ns |
| t_{THL}, t_{TLH} | output transition time | see Figure 5 | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | - | - | 75 | ns |
| | | $V_{CC} = 4.5 \text{ V}$ | - | - | 15 | ns |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | 13 | ns |
| $T_{amb} = -40 \text{ }^{\circ}\text{C to } +125 \text{ }^{\circ}\text{C}$ | | | | | | |
| t_{PHL}, t_{PLH} | propagation delay An to Bn; Bn to An | see Figure 5 | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | - | - | 135 | ns |
| | | $V_{CC} = 4.5 \text{ V}$ | - | - | 27 | ns |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | 23 | ns |
| t_{PZH}, t_{PLZ} | 3-state output enable time \overline{OEA} to An or Bn; OEB to An or Bn | see Figure 6 and 7 | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | - | - | 225 | ns |
| | | $V_{CC} = 4.5 \text{ V}$ | - | - | 45 | ns |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | 38 | ns |
| t_{PHZ}, t_{PLZ} | 3-state output disable time \overline{OEA} to An or Bn; OEB to An or Bn | see Figure 6 and 7 | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | - | - | 250 | ns |
| | | $V_{CC} = 4.5 \text{ V}$ | - | - | 50 | ns |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | 43 | ns |
| t_{THL}, t_{TLH} | output transition time | see Figure 5 | | | | |
| | | $V_{CC} = 2.0 \text{ V}$ | - | - | 90 | ns |
| | | $V_{CC} = 4.5 \text{ V}$ | - | - | 18 | ns |
| | | $V_{CC} = 6.0 \text{ V}$ | - | - | 15 | ns |

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

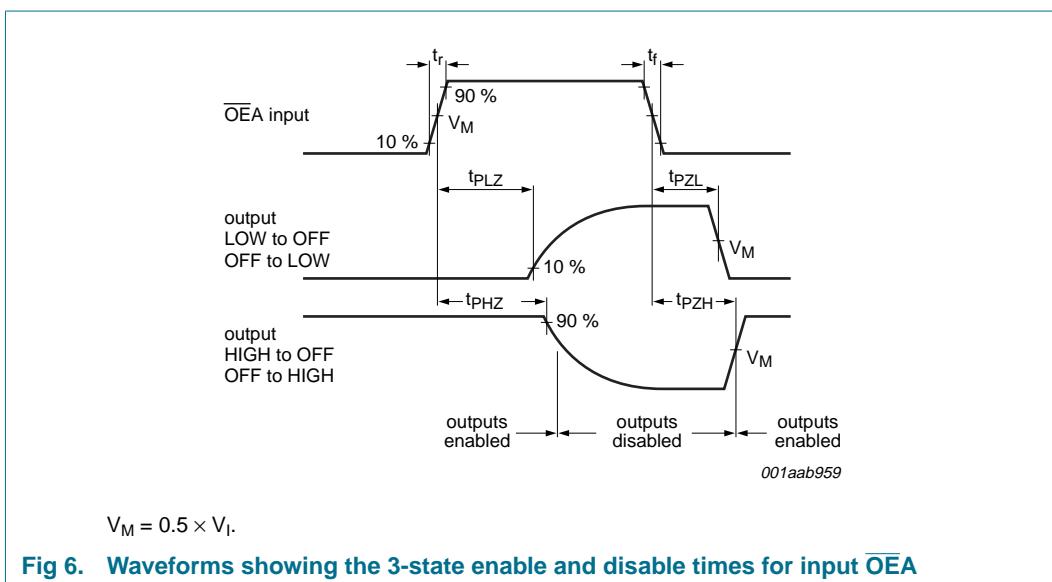
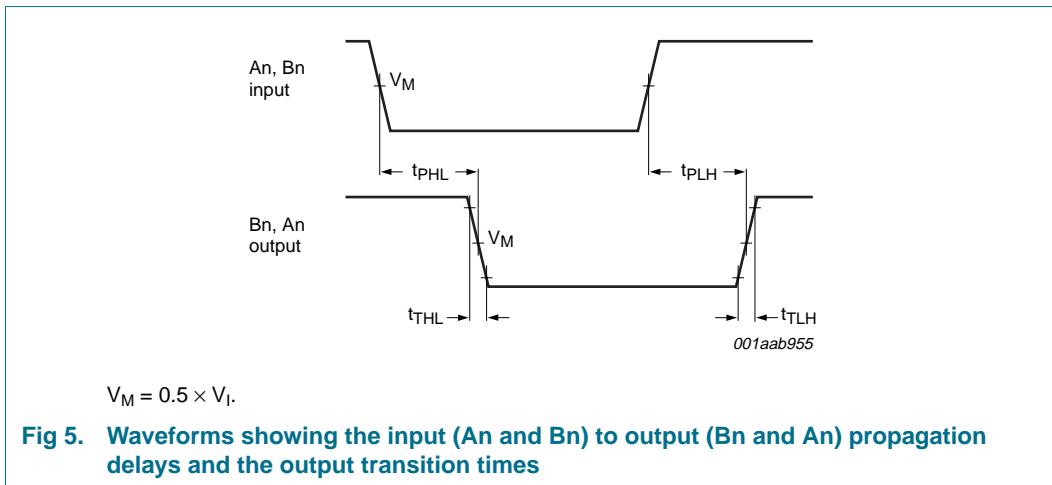
$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

 f_i = input frequency in MHz; f_o = output frequency in MHz; C_L = output load capacitance in pF; V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

12. Waveforms



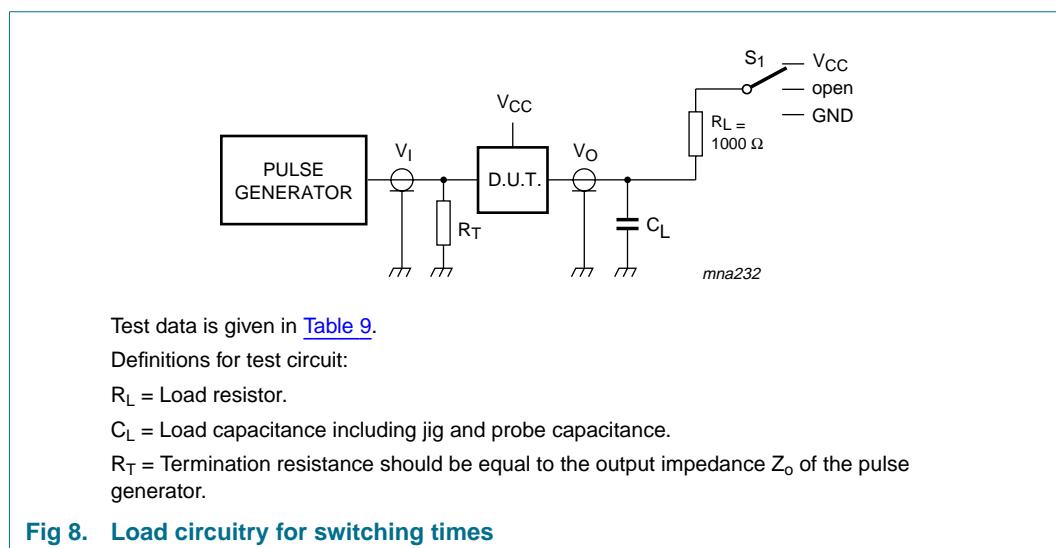
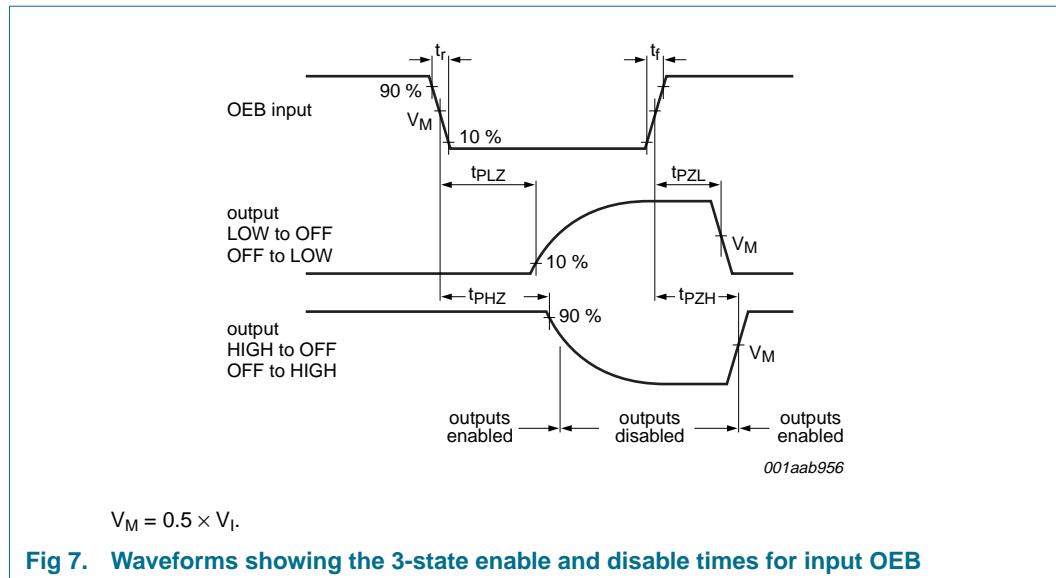


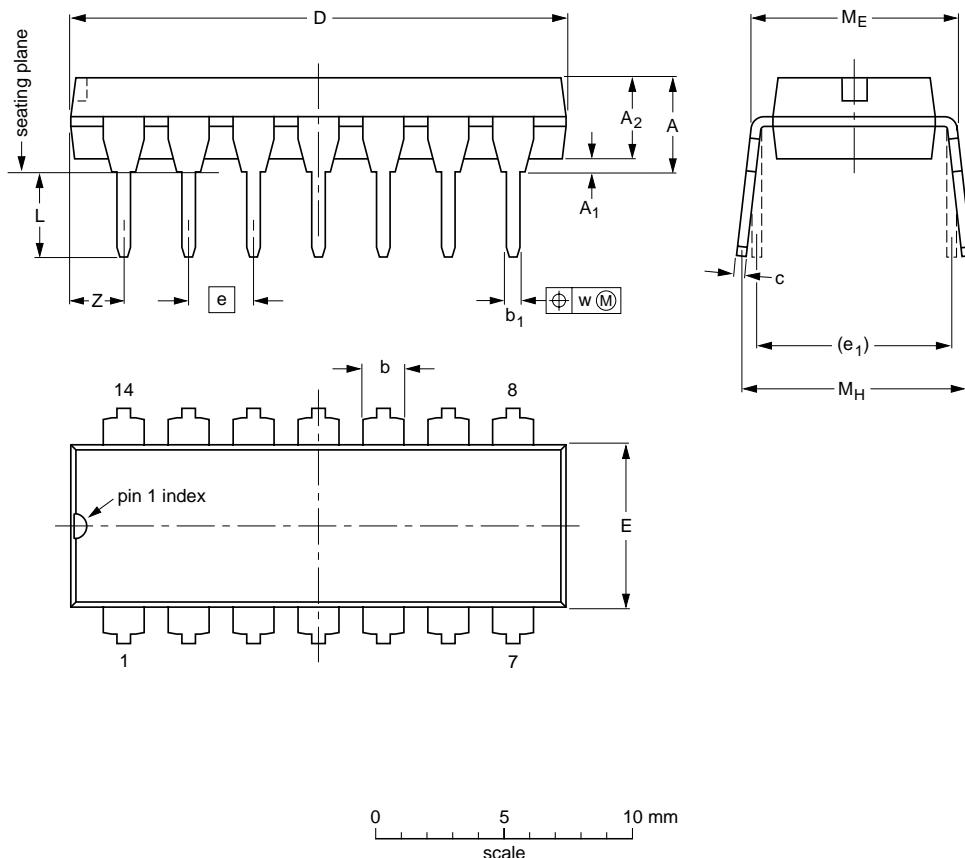
Table 9: Test data

| Supply | Input | | Load | | S_1 | | |
|----------|----------|-------------|-------|-------|--------------------|--------------------|--------------------|
| V_{CC} | V_I | $t_r = t_f$ | C_L | R_L | t_{PZL}, t_{PLZ} | t_{PZH}, t_{PHZ} | t_{PHL}, t_{PLH} |
| 2.0 V | V_{CC} | 6 ns | 50 pF | 1 kΩ | V_{CC} | GND | open |
| 4.5 V | V_{CC} | 6 ns | 50 pF | 1 kΩ | V_{CC} | GND | open |
| 6.0 V | V_{CC} | 6 ns | 50 pF | 1 kΩ | V_{CC} | GND | open |
| 5.0 V | V_{CC} | 6 ns | 15 pF | 1 kΩ | V_{CC} | GND | open |

13. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | A ₁ min. | A ₂ max. | b | b ₁ | c | D ⁽¹⁾ | E ⁽¹⁾ | e | e ₁ | L | M _E | M _H | w | Z ⁽¹⁾ max. |
|--------|-----------|------------------------|------------------------|----------------|----------------|----------------|------------------|------------------|------|----------------|--------------|----------------|----------------|-------|--------------------------|
| mm | 4.2 | 0.51 | 3.2 | 1.73 1.13 | 0.53 0.38 | 0.36 0.23 | 19.50 18.55 | 6.48 6.20 | 2.54 | 7.62 | 3.60 3.05 | 8.25 7.80 | 10.0 8.3 | 0.254 | 2.2 |
| inches | 0.17 | 0.02 | 0.13 | 0.068 0.044 | 0.021 0.015 | 0.014 0.009 | 0.77 0.73 | 0.26 0.24 | 0.1 | 0.3 | 0.14 0.12 | 0.32 0.31 | 0.39 0.33 | 0.01 | 0.087 |

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|--------|-----------|--|------------------------|----------------------|
| | IEC | JEDEC | JEITA | | | |
| SOT27-1 | 050G04 | MO-001 | SC-501-14 | | | 99-12-27 03-02-13 |

Fig 9. Package outline SOT27-1 (DIP14)

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

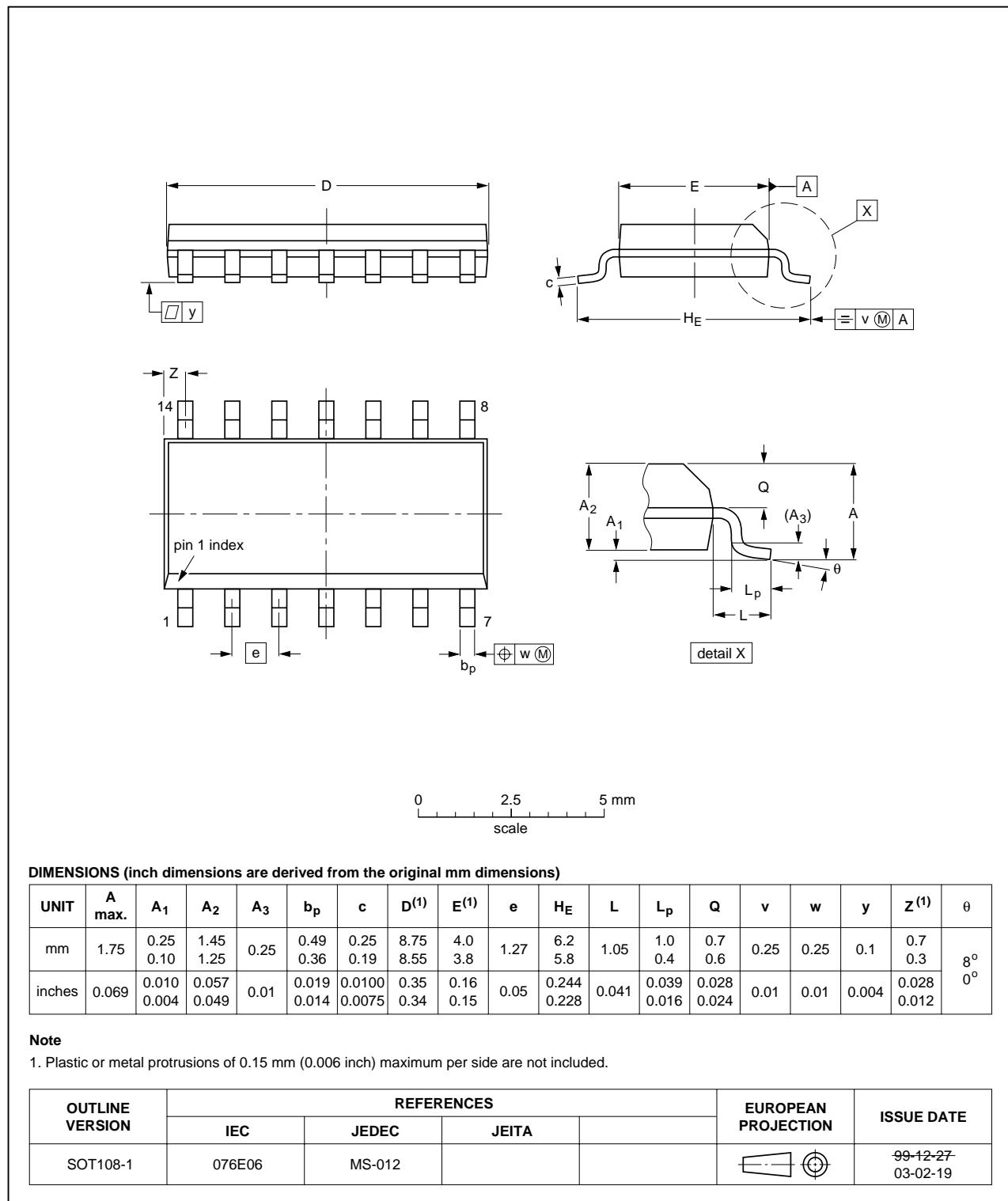


Fig 10. Package outline SOT108-1 (SO14)

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

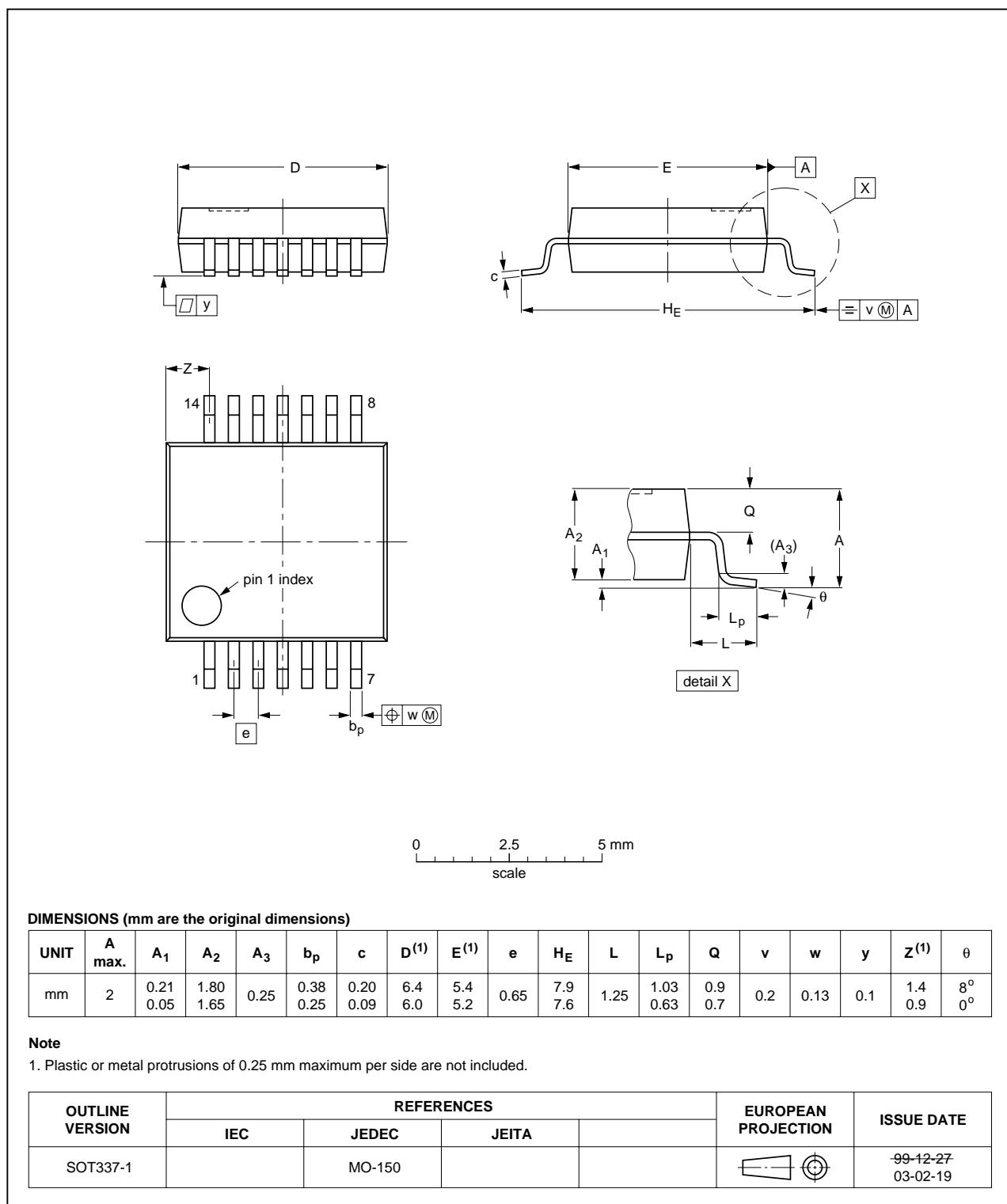


Fig 11. Package outline SOT337-1 (SSOP14)

14. Revision history

Table 10: Revision history

| Document ID | Release date | Data sheet status | Change notice | Doc. number | Supersedes |
|-------------------|--------------|-----------------------|---------------|----------------|--|
| 74HC243_3 | 20041112 | Product data sheet | - | 9397 750 13808 | 74HC_HCT243_CNV_2 |
| Modifications: | | | | | <ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the current presentation and information standard of Philips Semiconductors.• Removed type number 74HCT243.• Inserted family specification. |
| 74HC_HCT243_CNV_2 | 19970828 | Product specification | - | - | 74HC_HCT243_1 |
| 74HC_HCT243_1 | 19901201 | Product specification | - | - | - |

15. Data sheet status

| Level | Data sheet status [1] | Product status [2][3] | Definition |
|-------|-----------------------|-----------------------|--|
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
| II | Preliminary data | Qualification | This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product. |
| III | Product data | Production | This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). |

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL <http://www.semiconductors.philips.com>.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

16. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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18. Contact information

For additional information, please visit: <http://www.semiconductors.philips.com>

For sales office addresses, send an email to: sales.addresses@www.semiconductors.philips.com

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Date of release: 12 November 2004
Document number: 9397 750 13808

Published in The Netherlands

